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Docket: MXIC-P910270

IN THE UNITED STATES PATENT AND TRADEMARK OFFICE

In re application:

Chen et al.

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Examiner: Hoang, Quoc Dinh

U.S. Serial No: 10/661,089

Group Art Unit: 2818

Filed: September 10, 2003

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For: METHOD FOR MITIGATING CHEMICAL  
VAPOR DEPOSITION PHOSPHORUS  
DOPING OXIDE SURFACE INDUCED  
DEFECTS

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TRANSMITTAL

Sir:

I hereby certify that this correspondence is being deposited with the U.S. Postal Service with sufficient postage as first class mail in an envelope addressed to Commissioner for Patents, P.O. Box 1450, Alexandria, VA 22313-1450, or facsimile transmitted to: Commissioner for Patents at fax number (571) 273-8300 on December 23, 2005.

Submitted herewith are:

1. Return Receipt postcard;
2. Check No. 21626 in the amount of \$1020.00;
3. Amendment (9 pages);
4. Deposit Account Authorization: The Commissioner is hereby authorized to charge any needed fees to deposit account 50-1600.

Each of the 4 above-identified documents are enclosed herewith.

Respectfully submitted,

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## IN THE UNITED STATES PATENT AND TRADEMARK OFFICE

Applicant:	Chen et al.
Serial No.:	10/661,089
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Examiner: Hoang, Quoc Dinh  
Group Art Unit: 2818

Commissioner for Patents  
P.O. Box 1450  
Alexandria, VA 22313-1450

**AMENDMENT**

Dear Sir:

In response to the Office Action mailed June 28, 2005, Applicants respectfully request that the following amendments be entered in the above-identified patent application:

**Amendments to the Claims** are reflected in the listing of claims which begins on page 2 of this paper.

**Remarks/Arguments** begin on page 6 of this paper.